

N-Channel Super Junction Power MOSFET $\,\,{\rm IV}$

General Description

The series of devices use advanced trench gate super junction technology and design to provide ultra-low R_{DS(ON)} and low gate charge and With a rapid recovery body diode.This super junction MOSFET fits the industry's AC-DC SMPS requirements for PFC, AC/DC power conversion, industrial power applications,Fast charger, new energy vehicle charging pile, on-board OBC etc.

Features

- •New technology for high voltage device
- Ultra low on-resistance and ultra low conduction losses
- ●Ultra Low Gate Charge cause lower driving requirements
- Diode reverse recovery speed is super fast
- ●100% Avalanche Tested and 100% Trr Tested
- High reliability

ROHS compliant

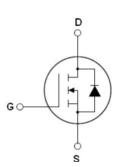
Application

- Power factor correction (PFC)
- Switched mode power supplies(SMPS)
- Uninterruptible Power Supply (UPS)
- On-board charger(OBC)
- LLC Half-bridge

Package Marking And Ordering Information

U	V	
Device	Device Package	Marking
NCE60NF040T	TO-247	NCE60NF040T





♦ Intrinsic fast-recovery body diode

Schematic diagram



Table 1. Absolute Maximum Ratings (Tc=25℃)

Parameter	Symbol	Value	Unit
Drain-Source Voltage (VGs=0V)	VDS	600	V
Gate-Source Voltage (V _{DS=0} V) ,AC (f>1 Hz)	Vgs	±30	V
Gate-Source Voltage (VDs=0V) ,DC	Vgs	±20	V
Continuous Drain Current at Tc=25°C	I _{D (DC)}	61	A
Continuous Drain Current at Tc=100°C	I _{D (DC)}	42.7	A
Pulsed drain current ^(Note 1)	I _{DM (pluse)}	183	A
Maximum Power Dissipation(Tc=25°C)	PD	411	W
Derate above 25°C		2.74	W/°C
Single pulse avalanche energy (Note 2)	Eas	484	mJ
Single pulse avalanche current (Note 2)	I _{AS}	11	A



Repetitive Avalanche energy , t _{AR} limited by T _{jmax} (Note 1)	E _{AR}	0.9	mJ
Reverse diode dv/dt, $V_{DS} \leq 480 \text{ V},I_{SD} < I_D$	dv/dt	50	V/ns
Drain Source voltage slope, $V_{DS} \leq 480 V$	dv/dt	50	V/ns
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55+175	°C

Table 2. Thermal Characteristic

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case (Maximum)	R _{thJC}	0.36	°C /W
Thermal Resistance, Junction-to-Ambient (Maximum)	R _{thJA}	62	°C /W

Table 3. Electrical Characteristics (TA=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Мах	Unit
On/off states						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =1mA 600				V
Zero Gate Voltage Drain Current(Tc=25°C)	I _{DSS}	V _{DS} =600V,V _{GS} =0V			15	μA
Zero Gate Voltage Drain Current(Tc=125°C)	I _{DSS}	V _{DS} =600V,V _{GS} =0V			400	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V			±200	nA
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =2mA	3.5	4.2	5	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =30.5A		35	40	mΩ
Dynamic Characteristics				1		
Gate Resistance	Rg	F=1MHZ, D-S short		2.6		Ω
Input Capacitance	Clss			5480		pF
Output Capacitance	Coss	V_{DS} =50V, V_{GS} =0V,		242		pF
Reverse Transfer Capacitance	Crss	F=1MHz		5.5		pF
Total Gate Charge	Qg			87		nC
Gate-Source Charge	Qgs	V _{DS} =480V,I _D =30.5A,V _{GS} =10		35		nC
Gate-Drain Charge	Q _{gd}			29		nC
Gate plateau voltage	Vgp			7.3		V
Switching times						
Turn-on Delay Time	t _{d(on)}			48		nS
Turn-on Rise Time	tr	V _{DD} =380V,I _D =30.5A,		18		nS
Turn-Off Delay Time	t _{d(off)}	R _G =3Ω,V _{GS} =10V		126		nS
Turn-Off Fall Time	t _f			15		nS
Source- Drain Diode Characteristics						
Source-drain current(Body Diode)	I _{SD}				61	А
Pulsed-Source-drain current(Body Diode)	I _{SDM}	T _c =25°C			183	А
Forward on voltage	V _{SD}	Tj=25°C,I _{SD} =61A,V _{GS} =0V		1.0	1.2	V
Reverse Recovery Time	t _{rr}			175		nS
Reverse Recovery Charge	Qrr	Tj=25°C,I⊧=30.5 A,		1.14		uC
Peak reverse recovery current	Irrm	di/dt=100A/µs		13		А

Notes: 1. Repetitive Rating: Pulse width limited by maximum junction temperature

2. Tj=25°C,VDD=50V,VG=10V, R_G=25 Ω

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TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS (curves)

Figure1. Safe operating area

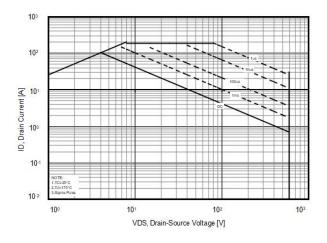
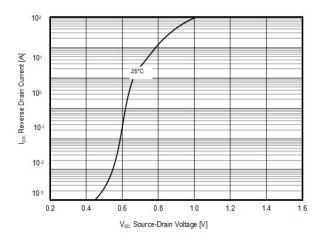
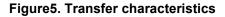


Figure3. Source-Drain Diode Forward Voltage





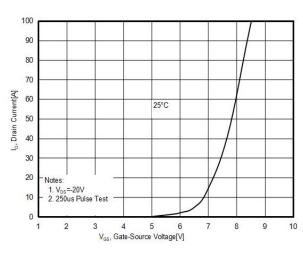


Figure2. Capacitance

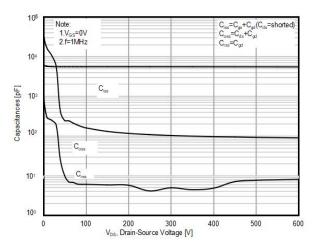
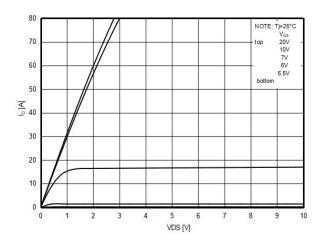
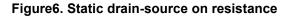
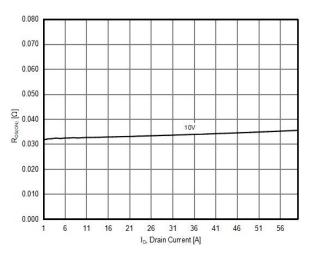


Figure4. Output characteristics









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Figure7. R_{DS(ON)} vs Junction Temperature

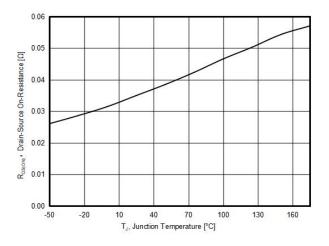


Figure8. BV_{DSS} vs Junction Temperature

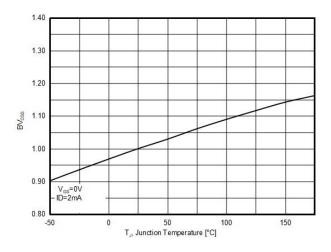


Figure9. Maximum I_{D} vs Junction Temperature

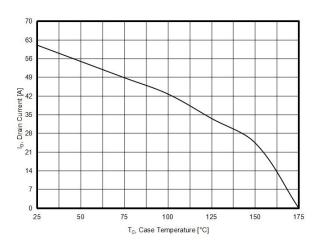
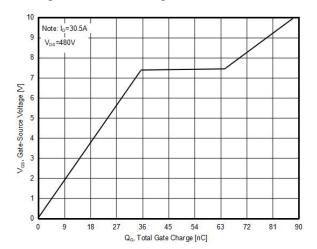


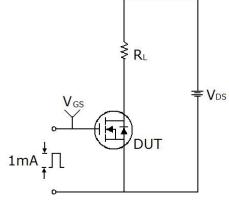
Figure10. Gate charge waveforms

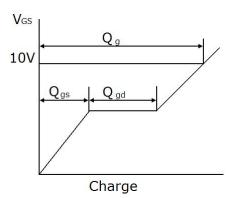




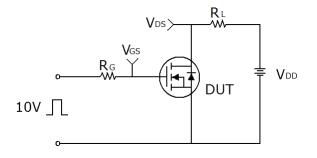
Test circuit

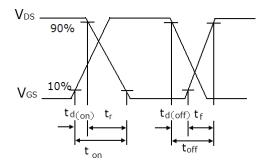
1) Gate charge test circuit & Waveform



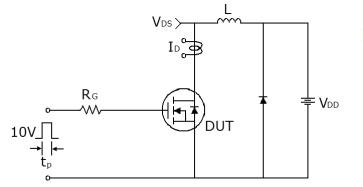


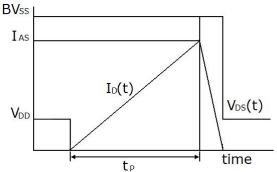
2) Switch Time Test Circuit:





3) Unclamped Inductive Switching Test Circuit & Waveforms

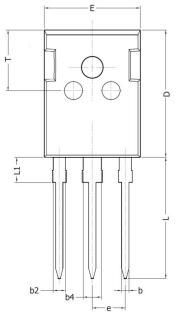


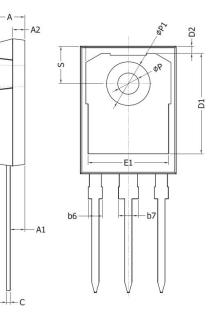


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TO-247-P Package Information

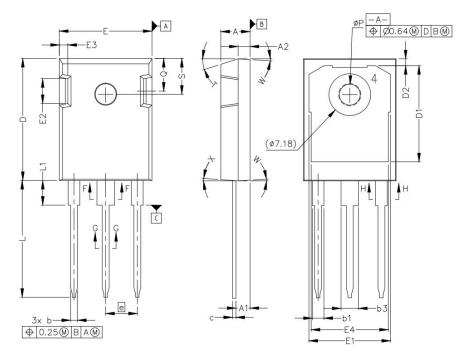




Dimensions In Millimeters			Dimensions In Inc	In Inches
Symbol	Min.	Max.	Min.	Max.
Α	4.90	5.10	0.193	0.201
A1	2.31	2.51	0.091	0.099
A2	1.90	2.10	0.075	0.083
b	1.16	1.26	0.046	0.050
b2	1.96	2.06	0.077	0.081
b4	2.96	3.06	0.117	0.120
b6	-	2.25	-	0.089
b7	-	3.25	-	0.128
с	0.59	0.66	0.023	0.026
D	20.90	21.10	0.823	0.831
D1	16.25	16.85	0.640	0.663
D2	1.05	1.35	0.041	0.053
E	15.70	15.90	0.618	0.626
E1	13.10	13.50	0.516	0.531
е	5.436	BSC	0.214	BSC
L	19.80	20.10	0.780	0.791
L1	-	4.30	-	0.169
Р	3.40	3.60	0.134	0.142
P1	7.00	7.40	0.276	0.291
S	6.05	6.25	0.238	0.246
Т	9.80	10.20	0.386	0.402



TO-247-B Package Information



0	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	4.83	5.21	0.190	0.205	
A1	2.29	2.54	0.090	0.100	
A2	1.91	2.16	0.075	0.085	
b	1.07	1.33	0.042	0.052	
b1	1.91	2.41	0.075	0.095	
b3	2.87	3.38	0.113	0.133	
С	0.55	0.68	0.022	0.027	
D	20.80	21.10	0.819	0.831	
D1	16.25	17.65	0.640	0.695	
D2	0.95	1.25	0.037	0.049	
E	15.75	16.13	0.620	0.635	
E1	13.10	14.15	0.516	0.557	
E2	3.68	5.10	0.145	0.201	
E3	1.00	1.90	0.039	0.075	
E4	12.38	13.43	0.487	0.529	
е	5.44	BSC	0.214 8	BSC	
N	3.0	00	0.11	8	
L	19.81	20.32	0.780	0.800	
L1	4.10	4.40	0.161	0.173	
Р	3.51	3.65	0.138	0.144	
Q	5.49	6.00	0.216	0.236	
S	6.04	6.30	0.238	0.248	

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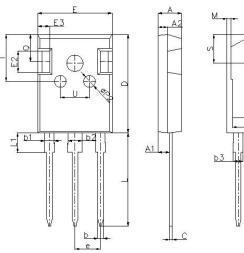
D1

E1

ПіСь4



TO-247-E Package Information



Currence al	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	4.90	5.10	0.193	0.201	
A1	2.31	2.51	0.091	0.099	
A2	1.90	2.10	0.075	0.083	
b	1.16	1.26	0.046	0.050	
b1	1.96	2.06	0.077	0.081	
b2	2.96	3.06	0.117	0.120	
b3	-	2.25	-	0.089	
b4	-	3.25	-	0.128	
С	0.59	0.66	0.023	0.026	
D	20.90	21.10	0.823	0.831	
D1	16.25	16.85	0.640	0.663	
D2	1.05	1.35	0.041	0.053	
E	15.70	15.90	0.618	0.626	
E1	13.10	13.50	0.516	0.531	
E2	4.40	4.60	0.173	0.181	
E3	2.40	2.60	0.094	0.102	
е	5.436	BSC	0.214B	SC	
L	19.80	20.10	0.780	0.791	
L1	-	4.30	-	0.169	
М	0.35	0.95	0.014	0.037	
Р	3.40	3.60	0.134	0.142	
P1	7.00	7.40	0.276	0.291	
P2	2.40	2.60	0.094	0.102	
Q	5.60	6.00	0.220	0.236	
S	6.05	6.25	0.238	0.246	
Т	9.80	10.20	0.386	0.402	
U	6.00	6.40	0.236	0.252	



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